



## Product Specification

### PE4220

**SPDT UltraCMOS™ RF Switch  
DC - 2500 MHz**

#### Features

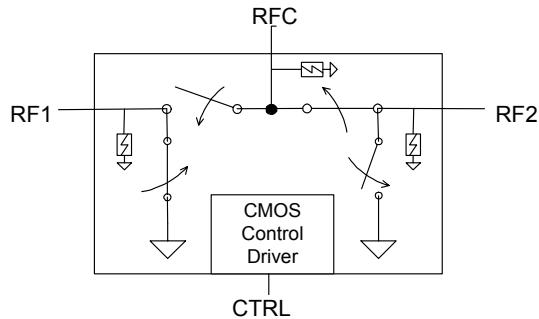
- Single 3-volt power supply
- Very low insertion loss: 0.25 dB at 1000 MHz
- High isolation: 37 dB at 1.0 GHz
- Typical input 1 dB compression point of +22.5 dBm
- Single-pin CMOS or TTL logic control
- Packaged in a small 8-lead MSOP

#### Product Description

The PE4220 UltraCMOS™ RF Switch is designed to cover a broad range of applications from near DC to 2500 MHz. This single-supply switch integrates on-board CMOS control logic driven by a simple, single-pin CMOS or TTL compatible control input. Using a nominal +3-volt power supply, a typical input 1 dB compression point of +22 dBm can be achieved. The PE4220 also exhibits input-output isolation of better than 37 dB at 1000 MHz and is offered in a small 8-lead MSOP package.

The PE4220 UltraCMOS™ RF Switch is manufactured in Peregrine's patented Ultra Thin Silicon (UTSi®) CMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

**Figure 1. Functional Diagram**



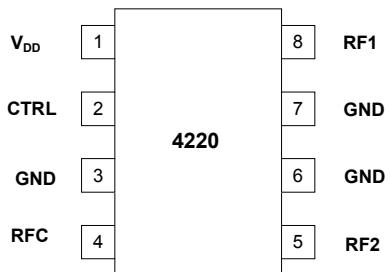
**Table 1. Electrical Specifications @ +25 °C, V<sub>DD</sub> = 3 V (Z<sub>S</sub> = Z<sub>L</sub> = 50 Ω)**

Parameter	Conditions	Minimum	Typical	Maximum	Units
Operating Frequency <sup>1</sup>		DC		2500	MHz
Insertion Loss	1000 MHz		0.25	0.35	dB
Isolation – RFC to RF1/RF2	1000 MHz	34.5	37		dB
Isolation – RF1 to RF2	1000 MHz	34	35		dB
Return Loss	1000 MHz	17.5	19		dB
'ON' Switching Time	CTRL to 0.1 dB final value, 2 GHz		200		ns
'OFF' Switching Time	CTRL to 25 dB isolation, 2 GHz		90		ns
Video Feedthrough <sup>2</sup>			5.0		mV <sub>pp</sub>
Input 1 dB Compression	2000 MHz	20	22.5		dBm
Input IP3	2000 MHz, 8 dBm	42	43.5		dBm

Notes:

1. Device linearity will begin to degrade below 10 MHz.

2. The DC transient at the output of any port of the switch when the control voltage is switched from Low to High or High to Low in a 50Ω test set-up, measured with 1ns risetime pulses and 500 MHz bandwidth.

**Figure 3. Pin Configuration (Top View)**

**Table 2. Pin Descriptions**

Pin No.	Pin Name	Description
1	V <sub>DD</sub>	Nominal 3 V supply connection. A bypass capacitor (100 pF) to the ground plane should be placed as close as possible to the pin
2	CTRL	CMOS or TTL logic level: High = RFC to RF1 signal path Low = RFC to RF2 signal path
3	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
4	RFC	Common RF port for switch (Note 1)
5	RF2	RF2 port (Note 1)
6	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
7	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
8	RF1	RF1 port (Note 1)

Note 1: All RF pins must be DC blocked with an external series capacitor or held at 0 V<sub>DC</sub>.

**Table 3. DC Electrical Specifications**

Parameter	Min	Typ	Max	Units
V <sub>DD</sub> Power Supply Voltage	2.7	3.0	3.3	V
I <sub>DD</sub> Power Supply Current (V <sub>DD</sub> = 3V, V <sub>CNTL</sub> = 3)		30	40	μA
Control Voltage High	0.7x V <sub>DD</sub>			V
Control Voltage Low			0.3x V <sub>DD</sub>	V

**Table 4. Absolute Maximum Ratings**

Symbol	Parameter/Conditions	Min	Max	Units
V <sub>DD</sub>	Power supply voltage	-0.3	4.0	V
V <sub>I</sub>	Voltage on any input	-0.3	V <sub>DD</sub> + 0.3	V
T <sub>ST</sub>	Storage temperature range	-65	150	°C
T <sub>OP</sub>	Operating temperature range	-40	85	°C
P <sub>IN</sub>	Input power (50Ω)		25	dBm
V <sub>ESD</sub>	ESD voltage (Human Body Model)		250	V

Absolute Maximum Ratings are those values listed in the above table. Exceeding these values may cause permanent device damage. Functional operation should be restricted to the limits in the DC Electrical Specifications table. Exposure to absolute maximum ratings for extended periods may affect device reliability.

#### Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating in Table 4.

#### Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

**Table 5. Control Logic Truth Table**

Control Voltage	Signal Path
CTRL = CMOS or TTL High	RFC to RF1
CTRL = CMOS or TTL Low	RFC to RF2

#### Control Logic

The control logic input pin (CTRL) is typically driven by a 3-volt CMOS logic level signal, and has a threshold of 50% of V<sub>DD</sub>. For flexibility to support systems that have 5-volt control logic drivers, the control logic input has been designed to handle a 5-volt logic HIGH signal. (A minimal current will be sourced out of the V<sub>DD</sub> pin when the control logic input voltage level exceeds V<sub>DD</sub>.)

## Evaluation Kit

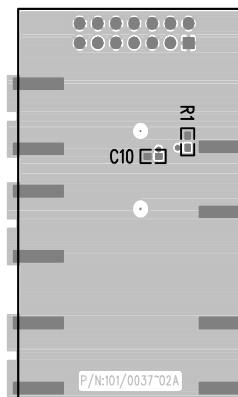
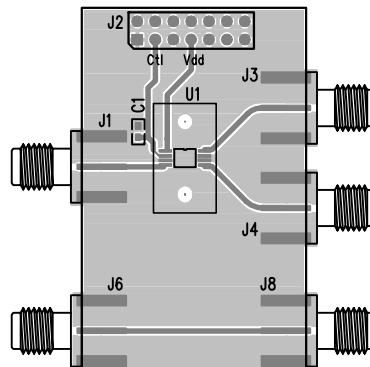
The SPDT Switch Evaluation Kit board was designed to ease customer evaluation of the PE4220 SPDT switch. The RF common port is connected through a  $50\ \Omega$  transmission line to the top left SMA connector, J1. Port 1 and Port 2 are connected through  $50\ \Omega$  transmission lines to the top two SMA connectors on the right side of the board, J3 and J4. A through transmission line connects SMA connectors J6 and J8. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide model with a trace width of 0.030", trace gaps of 0.007", dielectric thickness of 0.028", metal thickness of 0.0014" and  $\epsilon_r$  of 4.4. Note that the predominate mode for these transmission lines is coplanar waveguide with a ground plane.

J2 provides a means for controlling DC and digital inputs to the device. Starting from the lower left pin, the second pin to the right (J2-3) is connected to the device CTRL input. The fourth pin to the right (J2-7) is connected to the device  $V_{DD}$  input. A decoupling capacitor (100 pF) is provided on both CTRL and  $V_{DD}$  traces. It is the responsibility of the customer to determine proper supply decoupling for their design application. Removing these components from the evaluation board has not been shown to degrade RF performance.

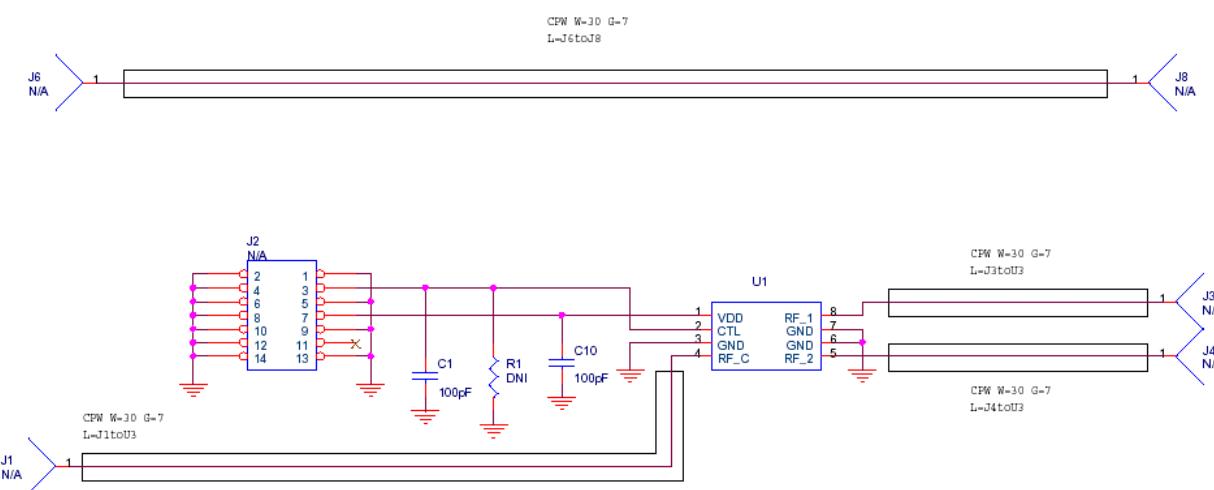
**Figure 4. Evaluation Board Layout**

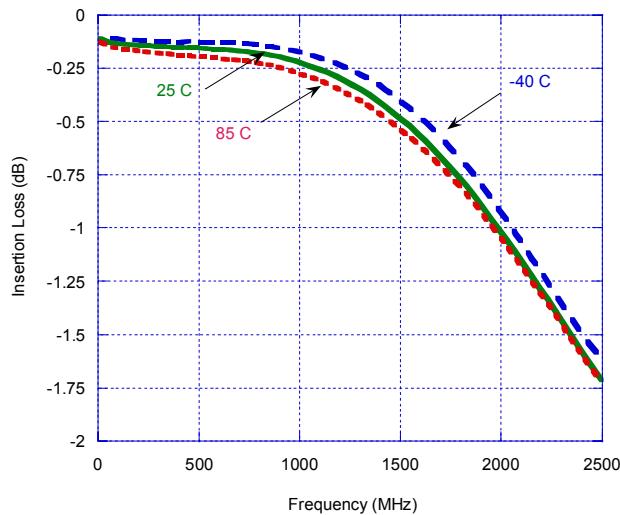
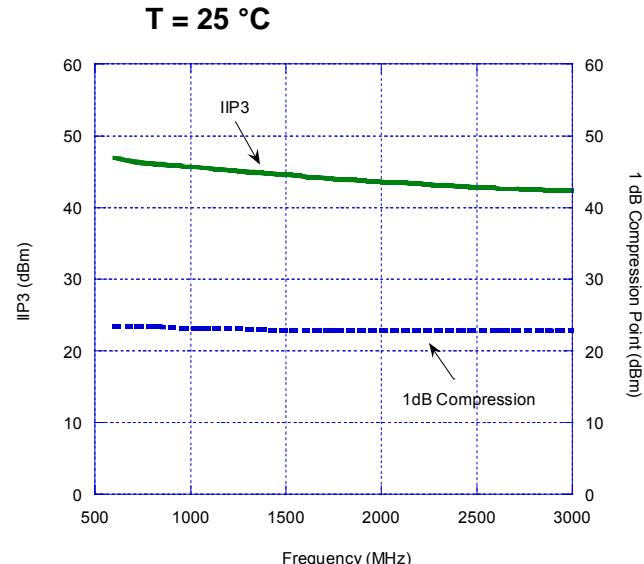
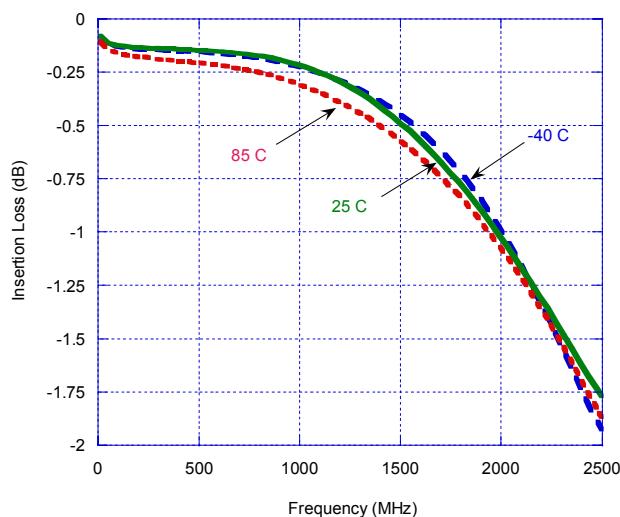
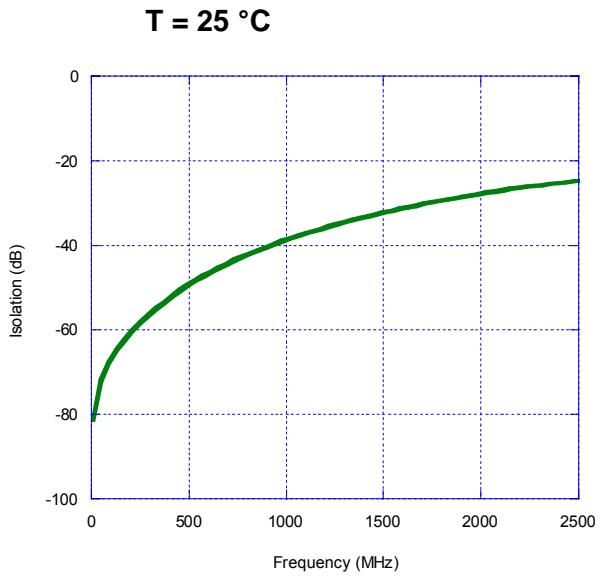
Peregrine specification 101/0037

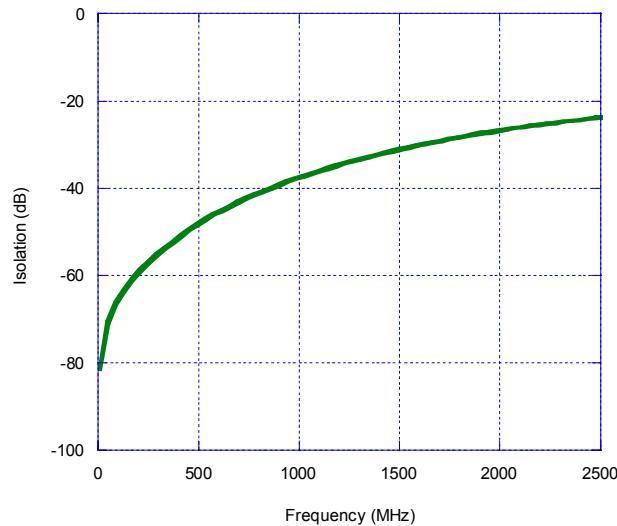
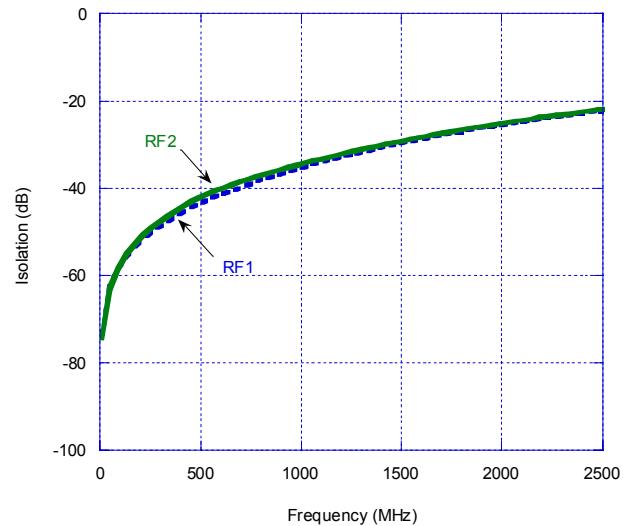
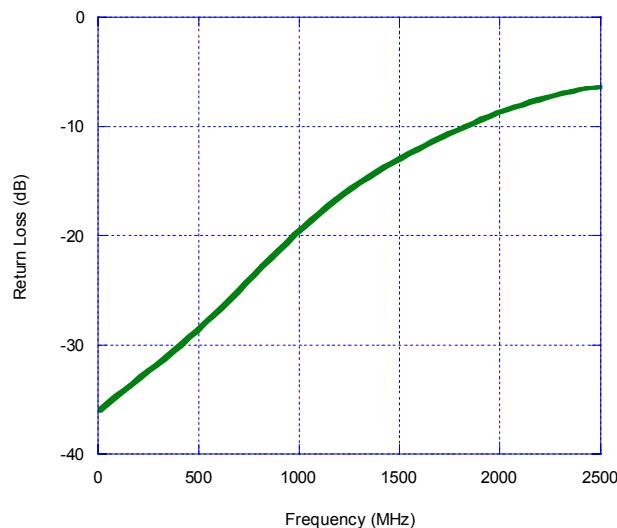
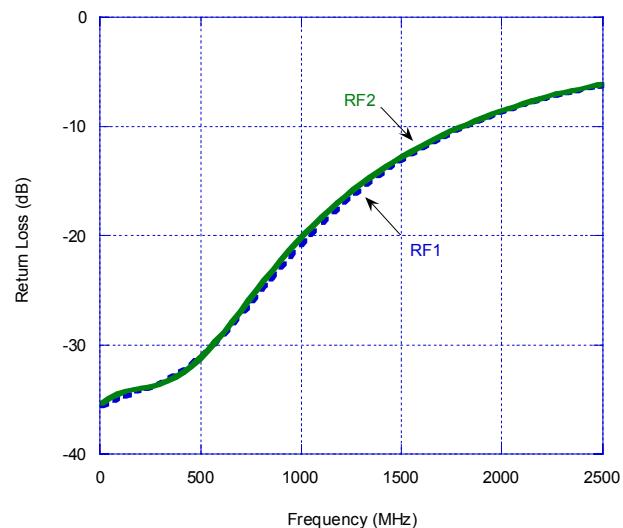


**Figure 5. Evaluation Board Schematic**

Peregrine specification 102/0035

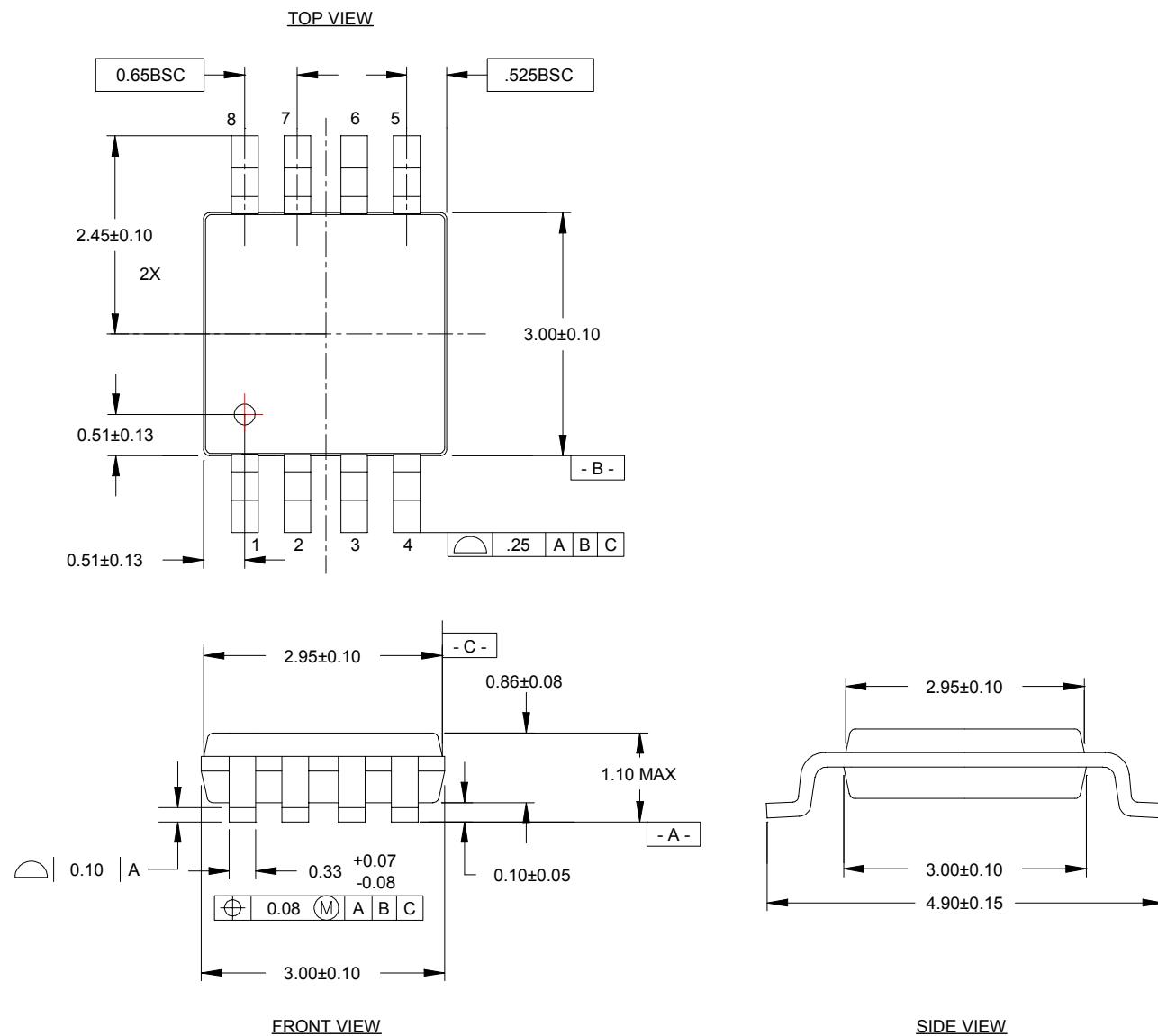


**Typical Performance Data @ -40 °C to 85 °C (Unless otherwise noted)**
**Figure 6. Insertion Loss – RFC to RF1**

**Figure 7. Input 1 dB Compression Point & IIP3**

**Figure 8. Insertion Loss – RFC to RF2**

**Figure 9. Isolation – RFC to RF1**


**Typical Performance Data @ 25 °C****Figure 10. Isolation – RFC to RF2****Figure 11. Isolation – RF1/RF2 to RF2/RF1****Figure 12. Return Loss – RFC****Figure 13. Return Loss – RF1, RF2**

**Figure 14. Package Drawing**

8-lead MSOP



## **Table 6. Ordering Information**

Order Code	Part Marking	Description	Package	Shipping Method
4220-21	4220	PE4220-08MSOP-50A	8-lead MSOP	50 units / Tube
4220-22	4220	PE4220-08MSOP-2000C	8-lead MSOP	2000 units / T&R
4220-00	PE4220-EK	PE4220-08MSOP-EK	Evaluation Kit	1 / Box
4220-51	4220	PE4220G-08MSOP-50A	Green 8-lead MSOP	50 units / Tube
4220-52	4220	PE4220G-08MSOP-2000C	Green 8-lead MSOP	2000 units / T&R

## Sales Offices

### The Americas

#### Peregrine Semiconductor Corp.

9450 Carroll Park Drive  
San Diego, CA 92121  
Tel 858-731-9400  
Fax 858-731-9499

### North Asia Pacific

#### Peregrine Semiconductor K.K.

5A-5, 5F Imperial Tower  
1-1-1 Uchisaiwaicho, Chiyoda-ku  
Tokyo 100-0011 Japan  
Tel: +81-3-3502-5211  
Fax: +81-3-3502-5213

### Europe

#### Peregrine Semiconductor Europe

##### *Commercial Products:*

Bâtiment Maine  
13-15 rue des Quatre Vents  
F- 92380 Garches, France  
Tel: +33-1-47-41-91-73  
Fax : +33-1-47-41-91-73

##### *Space and Defense Products:*

180 Rue Jean de Guiramand  
13852 Aix-En-Provence cedex 3, France  
Tel: +33(0) 4 4239 3361  
Fax: +33(0) 4 4239 7227

### South Asia Pacific

#### Peregrine Semiconductor

28G, Times Square,  
No. 500 Zhangyang Road,  
Shanghai, 200122, P.R. China  
Tel: +86-21-5836-8276  
Fax: +86-21-5836-7652

For a list of representatives in your area, please refer to our Web site at: [www.psemi.com](http://www.psemi.com)

## Data Sheet Identification

### Advance Information

The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

The information in this data sheet is believed to be reliable. However, Peregrine assumes no liability for the use of this information. Use shall be entirely at the user's own risk.

No patent rights or licenses to any circuits described in this data sheet are implied or granted to any third party.

Peregrine's products are not designed or intended for use in devices or systems intended for surgical implant, or in other applications intended to support or sustain life, or in any application in which the failure of the Peregrine product could create a situation in which personal injury or death might occur. Peregrine assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

The Peregrine name, logo, and UTSi are registered trademarks and UltraCMOS is a trademark of Peregrine Semiconductor Corp.

### Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

### Product Specification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a DCN (Document Change Notice).

SUNSTAR 商斯达实业集团是集研发、生产、工程、销售、代理经销、技术咨询、信息服务等为一体的高科技企业，是专业高科技电子产品生产厂家，是具有 10 多年历史的专业电子元器件供应商，是中国最早和最大的仓储式连锁规模经营大型综合电子零部件代理分销商之一，是一家专业代理和分销世界各大品牌 IC 芯片和电子元器件的连锁经营综合性国际公司，专业经营进口、国产名厂名牌电子元件，型号、种类齐全。在香港、北京、深圳、上海、西安、成都等全国主要电子市场设有直属分公司和产品展示展销窗口门市部专卖店及代理分销商，已在全国范围内建成强大统一的供货和代理分销网络。我们专业代理经销、开发生产电子元器件、集成电路、传感器、微波光电元器件、工控机/DOC/DOM 电子盘、专用电路、单片机开发、MCU/DSP/ARM/FPGA 软件硬件、二极管、三极管、模块等，是您可靠的一站式现货配套供应商、方案提供商、部件功能模块开发配套商。商斯达实业公司拥有庞大的资料库，有数位毕业于著名高校——有中国电子工业摇篮之称的西安电子科技大学（西军电）并长期从事国防尖端科技研究的高级工程师为您精挑细选、量身订做各种高科技电子元器件，并解决各种技术问题。

微波光电部专业代理经销高频、微波、光纤、光电元器件、组件、部件、模块、整机；电磁兼容元器件、材料、设备；微波 CAD、EDA 软件、开发测试仿真工具；微波、光纤仪器仪表。欢迎国外高科技微波、光纤厂商将优秀产品介绍到中国、共同开拓市场。长期大量现货专业批发高频、微波、卫星、光纤、电视、CATV 器件：晶振、VCO、连接器、PIN 开关、变容二极管、开关二极管、低噪晶体管、功率电阻及电容、放大器、功率管、MMIC、混频器、耦合器、功分器、振荡器、合成器、衰减器、滤波器、隔离器、环行器、移相器、调制解调器；光电子元器件和组件：红外发射管、红外接收管、光电开关、光敏管、发光二极管和发光二极管组件、半导体激光二极管和激光器组件、光电探测器和光接收组件、光发射接收模块、光纤激光器和光放大器、光调制器、光开关、DWDM 用光发射和接收器件、用户接入系统光光收发器件与模块、光纤连接器、光纤跳线/尾纤、光衰减器、光纤适配器、光隔离器、光耦合器、光环行器、光复用器/转换器；无线收发芯片和模组、蓝牙芯片和模组。

更多产品请看本公司产品专用销售网站：

商斯达微波光电产品网：<HTTP://www.rfoe.net/>

商斯达中国传感器科技信息网：<http://www.sensor-ic.com/>

商斯达工控安防网：<http://www.pc-ps.net/>

商斯达电子元器件网：<http://www.sunstare.com/>

商斯达消费电子产品网：<http://www.icasic.com/>

商斯达实业科技产品网：<http://www.sunstars.cn/> 射频微波光电元器件销售热线：

地址：深圳市福田区福华路福庆街鸿图大厦 1602 室

电话：0755-83396822 83397033 83398585 82884100

传真：0755-83376182 (0) 13823648918 MSN：[SUNS8888@hotmail.com](mailto:SUNS8888@hotmail.com)

邮编：518033 E-mail：[szss20@163.com](mailto:szss20@163.com) QQ：195847376

深圳赛格展销部：深圳华强北路赛格电子市场 2583 号 电话：0755-83665529 25059422

技术支持：0755-83394033 13501568376

欢迎索取免费详细资料、设计指南和光盘；产品凡多，未能尽录，欢迎来电查询。

北京分公司：北京海淀区知春路 132 号中发电子大厦 3097 号

TEL：010-81159046 82615020 13501189838 FAX：010-62543996

上海分公司：上海市北京东路 668 号上海赛格电子市场 D125 号

TEL：021-28311762 56703037 13701955389 FAX：021-56703037

西安分公司：西安高新区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL：029-81022619 13072977981 FAX:029-88789382